I) Amendments to the Specification

Please replace the paragraph beginning at page 4, line 18, with the following written paragraph:

A first field-oxide segment stripe over a third part of the channel region; wherein a first part of the first gate segment at least partially overlaps the first field-oxide segment stripe.

Please replace the paragraph beginning at page 4, line 23, with the following written paragraph:

In accordance with one aspect of the present invention, wherein the first gate segment and the first field-oxide segment stripe are substantially collinear.

Please replace the paragraph beginning at page 5, line 1, with the following written paragraph:

In accordance with one aspect of the present invention, further comprises a plurality of islands formed over the bulk and being enclosed encircled by the first doped region.

Please replace the paragraph beginning at page 5, line 11, with the following written paragraph:

In accordance with one aspect of the present invention, further comprises a second gate segment formed over a second part of the channel region; and a first part of the second gate segment overlaps at least partially the field-oxide segment stripe.

Please replace the paragraph beginning at page 6, line 11, with the following written paragraph:

A field-oxide segment stripe formed over the non-split-channel region; and the first and the second gate segments form a stack-gate structure.

Please replace the paragraph beginning at page 6, line 15, with the following written paragraph:

In accordance with one aspect of the present invention, wherein the first gate segment,

the second gate segment and the field-oxide segment stripe are substantially parallel to each other.

Please replace the paragraph beginning at page 7, line 3, with the following written paragraph:

In accordance with one aspect of the present invention, further comprises a plurality of islands formed over the bulk and being enclosed encircled by the first doped region.

Please replace the paragraph beginning at page 7, line 21, with the following written paragraph:

A first and a second arrays of islands formed over the bulk and being enclosed encircled by the first doped region; wherein